## **CoreEZ**<sup>®</sup>

CoreEZ<sup>®</sup> semiconductor package uses the HyperBGA<sup>®</sup> manufacturing platform to offer a thin core build up flip chip package with very dense core vias using a cost sensitive material set. The core via density provides 199 micron via to via core pitch, resulting in an essentially coreless structure.

High core via density is achieved using smaller pads and the same 50 micron laser drilled holes used in producing HyperBGA<sup>®</sup> to unblock wiring channels through the core. This enables CoreEZ<sup>®</sup> to provide up to twice the number of signal layers as a standard build up package that uses mechanically drilled core vias with large capture pads.

The end result is an extremely cost effective solution that allows full strip line signal layers on both sides of the core. Component cost is further reduced by enabling die shrink through die pad pitch reduction down to 150 microns.

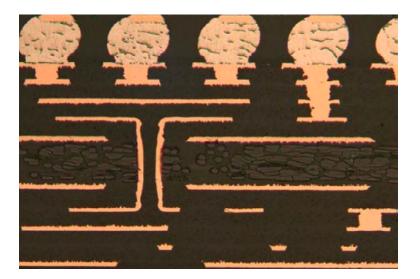
In addition, the thinness of the core provides improved power distribution and the ability to dissipate chip thermal power into the PCB.

CoreEZ<sup>®</sup> is an excellent choice for applications requiring low cost build up materials along with high reliability, performance and wireability. It is also well suited to aerospace applications requiring radiation tolerance.

#### DESCRIPTION

Up to 12 layer Particle Filled Epoxy Substrate

- Great solution for PCBA to SiP redesigns
- Very dense core vias (<200 micron pitch)</li>
- 50 micron UV laser drilled vias
- 25 micron trace/33 micron space
- High reliability
- Rad Hard



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# **CoreEZ® SPECIFICATIONS**

#### LAMINATE

Line width Line space Pad diameter Via diameter

Minimum die pad pitch Build-up dielectric thickness

#### MATERIALS

All Planes Dielectrics

Outer Dielectric Ground Plane Flip chip Pad Surface Finish

Wirebond Compatible BGA metallurgy ENEPIG Available BGA Metallurgy ENIG

#### ELECTRICAL

Build-up layer dielectric constant Build-up layer loss Core material dielectric constant Core material dielectric loss

#### PHYSICAL

Single chip body sizes System-in-package body size Number of I/Os JEDEC up to 55.0 mm Custom Up to 2916 at 1.0 mm smaller pitch possible

1,000 cycles of -55°

to 125°C

3.7 up to 2.5 GHz

3.7 up to 2.5 GHz

0.013 to 1 MHz

0.018 at 1 MHz

#### **REALIBILITY STRESS TESTING**

**Board level thermal cycles** 

High-temperature storage Component level thermal cycles

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www.ttm.com follow us on in f 25 μm minimum 25 μm minimum 100 μm minimum 50 μm minimum (UV laser drilled)

> 150 μm 35 μm, 50 μm

Copper P-Aramid in core and silica-filled high Tg epoxy Resin-Coated Copper Low-loss thermoset dielectric Copper-invar-copper Eutectic on ENIG, ENIG, lead free compatible on ENIG ENEPIG ENIG on copper, OSP on copper for wirebond ENIG on Copper, OSP on Copper, (ENIG) lead free compatible on ENIG



Over 4,000 cycles of 0° to 100°C 150°C for 1,000 hours Results may

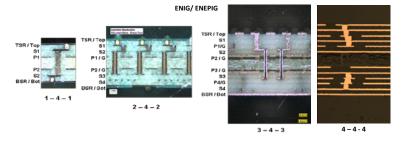
Results may vary with different die, assembly processing or design attributes.





#### CoreEZ® IS AVAILABLE AS A 1-4-1, 2-4-2, 3-4-3 OR 4-4-4 CROSS SECTIONS

- 1-4-1 = 2 full stripline signal planes, 4 pwr/gnd
- 2-4-2 = 4 dual stripline signal planes, 4 pwr/gnd
- 3-4-3 = 4 full stripline signal planes, 6 power/gnd
- 4-4-4 = 4 full stripline signal planes, 8 pwr/gnd



Attribute	HDI: Hyper <sup>®</sup> (PTFE)	HDI: CoreEZ® (Particle Filled Epoxy) BGA, Custom Pin Array	
PCB Attach	BGA, Custom Pin Array		
Die attach	Wirebondable, Flip Chip up to 20mm, SMT	Wirebondable, Flip Chip up to 17mm, SMT	
Radiation Level	Rad Tolerant	Strategic Rad Hard	
Embedded Passives	Yes	Yes	
FC Component level reliability (-55 to 125*C)	250 cycles	1000 cycles	
FC Board level reliability (0 to 100*C)	10,000 cycles	5,000 cycles	
Composite CTE	16-18ppm	18ppm, 16ppm for 2-4-2	
Er	2.7	3.7	
Loss Tan	.003 .016		

#### SUBSTRATE PRODUCT ATTRIBUTES

Attribute	HDI: CoreEZ® (Particle Filled Epoxy)
C4 Pitch (Minimum)	180 microns nominal, 150 $\mu m$ possible for specific applications
Line width (Minimum)	25 microns *
Line space (Minimum)	30 microns *
Core Via type	laser
Core Via Diameter	50 microns
Build Up Via	laser
Build Up Via diameter	50 microns
Stacked vias	Build up only
Capture pad diameter (Typical)	100 microns
Surface finish	ENIG/ ENEPIG
Solder mask	Yes
Thickness	.5mm
Layers	12



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### CoreEZ® RELIABILITY TESTING

Stress Test	Duration Required to Pass	2-4-2 Substrates	2-4-2 Modules 14.7mm Die / 42.5 Pkg	3-4-3 Modules 17.3 Die / 42.5 Pkg	4-4-4 Substrates	4-4-4 Modules 17.3 Die / 50 Pkg
Board level (ATC) (0 to 100°C)	3600 Cycles	No fails @ 3600 cycles	No fails @ 5000 cycles	No fails @ 3500 cycles	No fails @ 5000 cycles	
Component level (DTC) (-55 to + 125°C)	1000 Cycles	No fails @ 2000 cycles		No fails @ 2000 cycles	No fails @ 2000 cycles	No fails @ 2000 cycles
Component level (DTC) (-40 to + 125°C)	1000 Cycles	No fails @ 2000 cycles		No fails @ 2000 cycles		
Component level (DTC) (-55 to + 110°C)	1000 Cycles			No fails @ 2000 cycles		
Wet Thermal Shock (-55 to + 125°C)	100 Cycles	No fails @ 2000 cycles			No fails @ 1000 cycles	No fails @ 750 cycles
High Temp Storage (150°C)	1000 hours				No fails @ 1000 hours	No fails @ 1000 hours
High Temp Storage (125°C)	1000 hours	No fails @ 2023 hours				
Unbiased HAST (110°C / 85% RH)	264 hours	No fails @ 264 hours			No fails @ 264 hours	No fails @ 288 hours
Temp/Humidity & Bias (85°C / 85%RH / 3.7V	1000 hours	No fails @ 1000 hours				
High Temp Operating Life 125C/3.5vdc/1000hrs	1000 hours				1000 hrs no fails	

